

2814 #

Docket: 0756-1896

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re PATENT Application of
Hishashi OHTANI et al.

Serial No.: 09/197,767

Filed: November 23, 1998

For: SEMICONDUCTOR DEVICE AND
PROCESS FOR PRODUCING THE SAME



Art Unit: 2814

Examiner: P. Cao

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as First Class Mail in an envelope addressed to: Assistant Commissioner for Trademarks, 2000 Crystal Drive, Arlington, VA 22202-3513, on 12-6-00.

Heidi M. Schuler

TRANSMITTAL LETTER

Assistant Commissioner for Patents
Washington, D.C. 20231

Sir:

Transmitted herewith is an Amendment, a Petition for Extension of Time, and a Transmittal Letter in the above-identified application.

The fees have been calculated as shown below:

	Claims Remaining After Amendment		Highest Number Previously Paid For	Present Extra	Small/Large Entity Rate	Fee
Total	54	Minus	76	0	x \$9/\$18	\$.00
Indep	6	Minus	10	0	x \$40/\$80	\$.00
First Presentation of Multiple Dependent Claim					+ \$135/\$270	\$.00
TOTAL						\$.00

- [X] A check in the amount of \$890.00 to cover the extension fee is enclosed.
- [X] In the event applicant(s) has overlooked the need for any petition and fee for extension of time, and such extension is required, applicant(s) requests that this be considered a petition therefor and that such fee be charged to Deposit Account No. 19-2380.
- [X] The Commissioner is hereby authorized to charge fees under 37 CFR 1.16, 1.17, 1.20(a), 1.20(b), 1.20(c) and 1.20 (d) (except the Issue Fee) which may be required now or hereafter, or credit any overpayment, to Deposit Account No. 19-2380. A duplicate copy of this sheet is attached.

Respectfully submitted,

NIXON PEABODY LLP



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EJR/CTB/lfm

Attorney Docket No.: 0756-1896

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I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as First Class Mail in an envelope addressed to Assistant Commissioner for Patents, 2700 Crystal Drive, Arlington, Virginia 22202-4302, on 12-12-00.

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AMENDMENT

Honorable Commissioner for Patents
Washington, D.C. 20231

Sir:

In response to the Office Action dated June 6, 2000, the period for reply extended by the attached Petition for Extension of Time, please amend the above-identified application as follows:

IN THE CLAIMS:

Please cancel claims 11-12, 17-21, and 41-45 without prejudice.

Please amend claims 1-16, 22-27 and 40 as follows:

1. (Amended) A semiconductor device comprising:

at least one transistor;

at least one interlayer insulating film formed over said transistor, said interlayer insulating film having at least one contact hole;

[two conductive layers provided as separate layers;]

[an insulating layer sandwiched by said two conductive layers; and]

an embedded conductive layer provided to fill [an opening formed in said insulating layer] said contact hole wherein a top surface of said embedded conductive layer is flush with a top surface of said interlayer insulating film[.]; and